


### 25.0 Amps Single Phase Full Wave

### Bridge Rectifier

#### Features

- Diode chips are glass passivated
- Suitable for Universal hole mounting
- Easy to assemble & install on P.C.B.
- High Surge Current Capability
- High Isolation between terminals and molded case ( $2500 V_{RMS}$ )
- High Thermal Conductivity
- Lead free terminals solderable as per MIL-STD-750, Method 2026
- High Temperature soldering guaranteed at  $260^{\circ}C/ 8-10secs$
- UL E160375 approved 

$$I_{O(AV)} = 25A$$

$$V_{RRM} = 200/ 800V$$

#### Description

These IRXB..H Series of Single Phase Bridges consist of four glass passivated silicon junction connected as a Full Wave Bridge. These four junctions are encapsulated by plastic molding technique. These Bridges are mainly used in Switch Mode power supply, Induction cooker, Airconditioner, Washing Machine and Microwave oven.

#### Major Ratings and Characteristics

| Parameters      | IR25XB..H   | Units       |
|-----------------|-------------|-------------|
| $I_O$           | 25          | A           |
| @ $T_C$         | 100         | $^{\circ}C$ |
| $I_{FSM}$       | @50Hz 400   | A           |
|                 | @60Hz 420   | A           |
| $I^2t$          | @50Hz 800   | $A^2s$      |
|                 | @60Hz 732   | $A^2s$      |
| $V_{RRM}$ range | 200 to 800  | V           |
| $T_J$           | - 55 to 150 | $^{\circ}C$ |



IR25XB..H

**ELECTRICAL SPECIFICATIONS**

## Voltage Ratings

| Type number | Voltage Code | $V_{RRM}$ , max repetitive peak rev. voltage<br>$T_J = T_J \text{ max.}$<br>V | $V_{RMS}$ , max RMS voltage<br>$T_J = T_J \text{ max.}$<br>V | $V_{RSM}$ , max non-repetitive peak rev. voltage<br>$T_J = T_J \text{ max.}$<br>V | $I_{RRM}$ max.<br>@ rated $V_{RRM}$<br>$T_J = 25^\circ\text{C}$<br>$\mu\text{A}$ | $I_{RRM}$ max.<br>@ rated $V_{RRM}$<br>$T_J = 150^\circ\text{C}$<br>$\mu\text{A}$ |
|-------------|--------------|---|--|---|--|---|
| IR25XB..H   | 02           | 200   | 140  | 275   | 5  | 250   |
|             | 04           | 400   | 280  | 500   | 5  | 250   |
|             | 06           | 600   | 420  | 725   | 5  | 250   |
|             | 08           | 800   | 560  | 900   | 5  | 250   |

**Forward Conduction**

| Parameters  | IR25XB..H  | Unit                 | Conditions   |
|---|------------|----------------------|--|
| $I_O$ Maximum DC output current   | 25         | A                    | $T_C = 100^\circ\text{C}$ , Resistive & inductive load |
| $I_{FSM}$ Maximum peak, one-cycle non-repetitive surge current, following any rated load condition and with rated $V_{RRM}$ reapplied | 400        |                      | $t = 10\text{ms}$                                      |
|   | 420        | $t = 8.3\text{ms}$   |  |
| $I^2t$ Maximum $I^2t$ for fusing, initial $T_J = T_J \text{ max}$   | 800        | $\text{A}^2\text{s}$ | $t = 10\text{ms}$                                      |
|   | 732        |                      | $t = 8.3\text{ms}$                                     |
| $V_{FM}$ Maximum peak forward voltage per diode   | 0.975      | V                    | $T_J = 25^\circ\text{C}$ , $I_{FM} = 12.5\text{A}$     |
| $I_{RM}$ Typical peak reverse leakage current t per diode   | 5.0        | $\mu\text{A}$        | $T_J = 25^\circ\text{C}$ , 100% $V_{RRM}$              |
|   | 250        |                      | $T_J = 150^\circ\text{C}$ , 100% $V_{RRM}$             |
| $V_{RRM}$ Maximum repetitive peak reverse voltage range   | 200 to 800 | V                    |  |

**Thermal and Mechanical Specifications**

| Parameters  | IR25XB..H  | Unit                      | Conditions              |
|---|------------|---------------------------|-------------------------|
| $T_J$ Operating and storage temperature range       | -55 to 150 | $^\circ\text{C}$          |                         |
| $R_{thJC}$ Max. thermal resistance junction to case | 1.0        | $^\circ\text{C}/\text{W}$ | At DC rated current (1) |
| $R_{thJA}$ Thermal resistance, junction to ambient  | 22         | $^\circ\text{C}/\text{W}$ | At DC rated current (2) |
| W Approximate weight                                | 7.4 (0.26) | g (oz)                    |                         |
| T Mounting Torque                                   | 1.0        | Nm                        | Bridge to Heatsink      |
|   | 9.0        | Lb.in                     |                         |

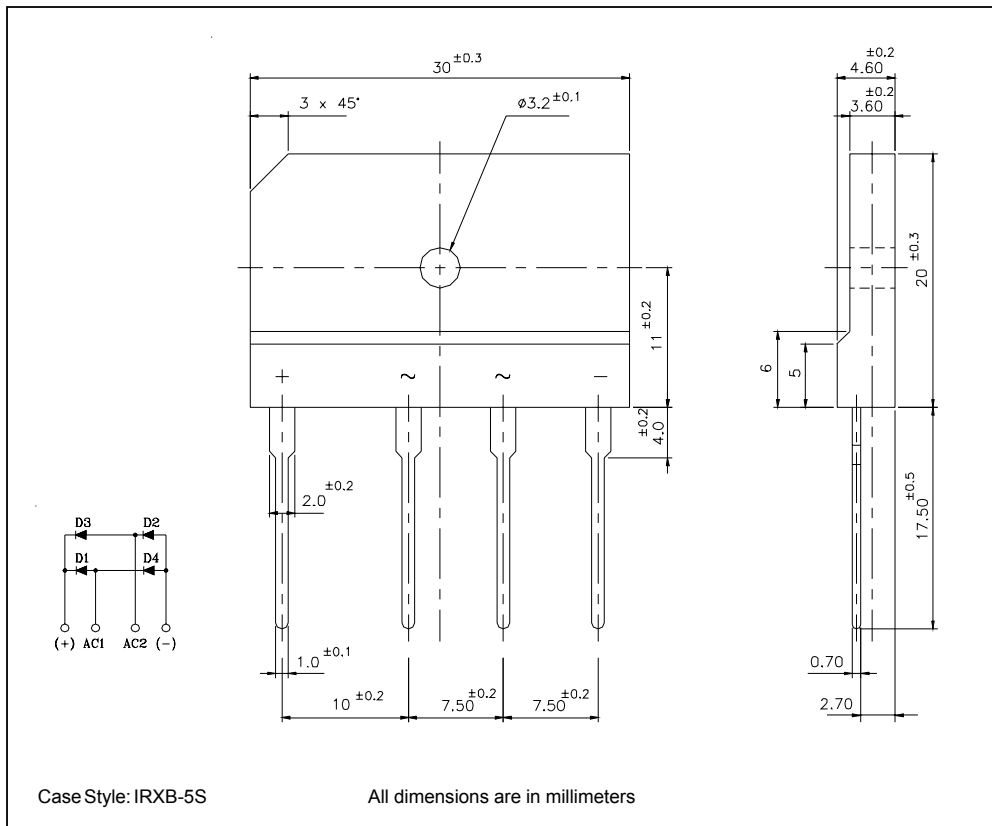
Note (1): Bridge mounted on Aluminum heat sink, use silicon thermal compound for heat transfer and bolt down using 3mm screw

(2): Bridges mounted in free air without heatsink.

**Ordering Information Table**

|             |  |           |           |          |
|-------------|--|-----------|-----------|----------|
| Device Code |  |           |           |          |
| <b>IR</b>   | <b>25</b>                              | <b>XB</b> | <b>08</b> | <b>H</b> |
| ①           | ②                                      | ③         | ④         | ⑤        |
| <b>1</b>    | - International Rectifier              |           |           |          |
| <b>2</b>    | - Bridge Current - 25Amps              |           |           |          |
| <b>3</b>    | - 10-7.5mm spacing                     |           |           |          |
| <b>4</b>    | - Voltage Code: code x 100 = $V_{RRM}$ |           |           |          |
| <b>5</b>    | - H = High Surge                       |           |           |          |

**Outline Table**



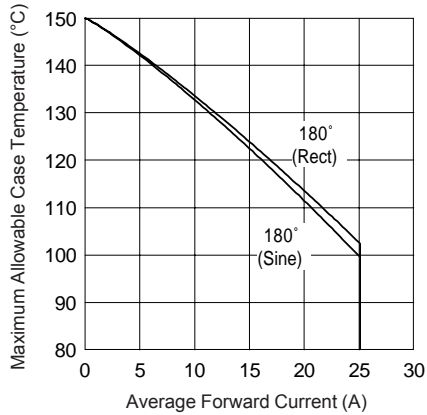


Fig. 1 - Current Ratings Characteristics

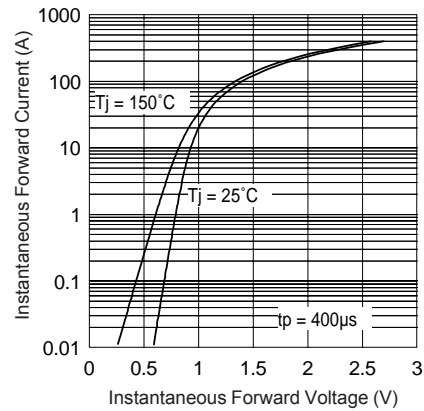


Fig. 2 - Forward Voltage Drop Characteristics

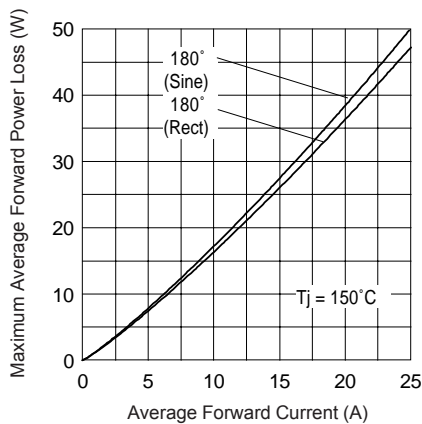


Fig. 3 - Total Power Loss Characteristics

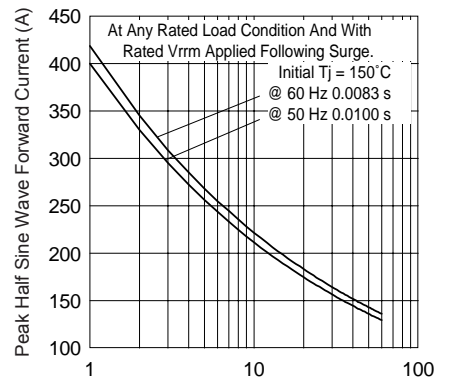


Fig. 4 - Maximum Non-Repetitive Surge Current

Data and specifications subject to change without notice.  
This product has been designed and qualified for Industrial and Consumer Level.  
Qualification Standards can be found on IR's Web site.